

L Number	Hits	Search Text	DB	Time stamp
-	351	esd same (layer layers) same (well wells)	USPAT	2003/09/30 20:32
-	37	esd same (layer layers) same (well wells) same lateral	USPAT	2003/09/30 20:32
-	17932	esd same (layer layers) same (well wells) same lateral (scr (silicon adj controlled adj rectifier))	USPAT	2003/09/30 20:33
-	14	esd same (layer layers) same (well wells) same lateral same (scr (silicon adj controlled adj rectifier))	USPAT	2003/09/30 20:33
-	249	lateral same (scr (silicon adj controlled adj rectifier))	USPAT	2003/09/30 20:36
-	101	lateral same (scr (silicon adj controlled adj rectifier)) same (well wells)	USPAT	2003/09/30 20:36
-	95	(lateral same (scr (silicon adj controlled adj rectifier)) same (well wells)) and substrate	USPAT	2003/09/30 20:37
-	78	lateral adj (scr (silicon adj controlled adj rectifier))	USPAT	2003/09/30 20:36
-	45	lateral adj (scr (silicon adj controlled adj rectifier)) same (well wells)	USPAT	2003/09/30 20:37
-	43	(lateral adj (scr (silicon adj controlled adj rectifier)) same (well wells)) and substrate	USPAT	2003/09/30 21:05
-	1263	(257/110,355,362,356,357).CCLS.	USPAT	2003/09/30 21:06
-	0	("L1land(lateraladj(scr(siliconadjcontrolledadjrectifier))	USPAT	2003/09/30 21:07
-	26	((257/110,355,362,356,357).CCLS.) and (lateral adj (scr (silicon adj controlled adj rectifier)))	USPAT	2003/09/30 21:07